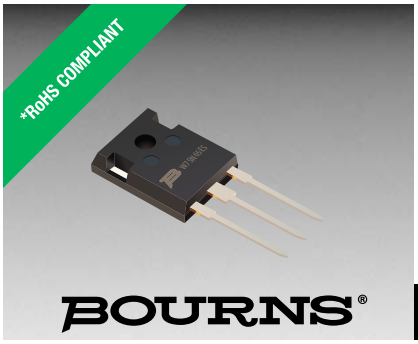


Features

- 650 V, 75 A, Low Collector-Emitter Saturation Voltage ($V_{CE(sat)}$)
- Novel trench-gate field-stop technology
- Optimized for conduction
- Medium speed switching
- Maximum operating T_j = 175 °C
- RoHS compliant*

Applications

- Switch-Mode Power Supplies (SMPS)
- Uninterruptible Power Sources (UPS)
- Power Factor Correction (PFC)
- Inverters
- Welding converters
- Photovoltaic

BIDW75N65ES5 Insulated Gate Bipolar Transistor (IGBT)

General Information

The Bourns® Model BIDW75N65ES5 IGBT device combines technology from a MOS gate and a bipolar transistor, resulting in an optimum component for high voltage and high current applications. This device uses Trench-Gate Field-Stop technology providing greater control of dynamic characteristics while resulting in a lower Collector-Emitter Saturation Voltage ($V_{CE(sat)}$) and fewer switching losses.

Additional Information

Click these links for more information:

PRODUCT SELECTOR | TECHNICAL LIBRARY | INVENTORY | SAMPLES | CONTACT

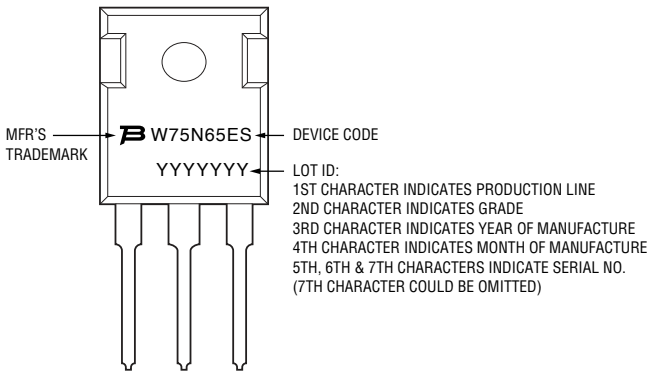
Maximum Electrical Ratings (T_C = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CES}	650	V
Continuous Collector Current (T_C = 25 °C), limited by T_{jmax}	I_C	150	A
Continuous Collector Current (T_C = 100 °C), limited by T_{jmax}	I_C	75	A
Pulsed Collector Current, t_p limited by T_{jmax}	I_{CP}	300	A
Gate-Emitter Voltage	V_{GE}	±20	V
Transient Gate-Emitter Voltage ($t_p \leq 10\ \mu s$, D < 0.01)	V_{GE}	±30	V
Continuous Forward Current (T_C = 100 °C), limited by T_{jmax}	I_F	75	A
Total Power Dissipation	P_{total}	394	W
Storage Temperature	T_{STG}	-55 to +150	°C
Operating Junction Temperature	T_j	-40 to +175	°C

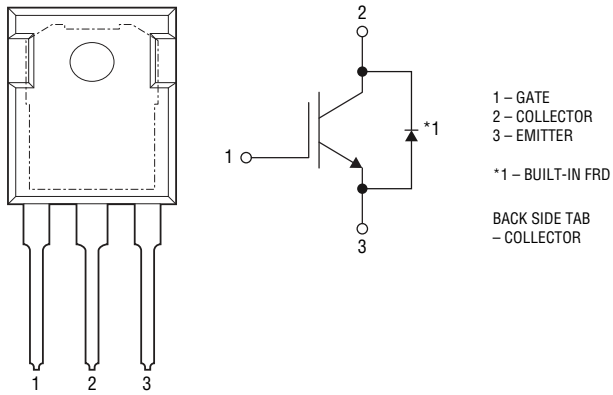
Thermal Resistance

Parameter	Symbol	Max	Unit
IGBT Thermal Resistance Junction - Case	$R_{th(j-c)\_IGBT}$	0.38	°C/W
Diode Thermal Resistance Junction - Case	$R_{th(j-c)\_Diode}$	0.4	°C/W

Typical Part Marking



Internal Circuit



WARNING Cancer and Reproductive Harm
www.P65Warnings.ca.gov

*RoHS Directive 2015/863, Mar 31, 2015 and Annex.
Specifications are subject to change without notice.
Users should verify actual device performance in their specific applications.
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Static Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Collector-Emitter Breakdown Voltage	BV_{CES}	V_{GE} = 0 V, I_C = 250 µA	650	—	—	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_{GE} = 15 V, I_C = 75 A, T_C= 25 °C	—	1.42	1.85	V
		V_{GE} = 15 V, I_C = 75 A, T_C= 150 °C	—	1.67	—	
Diode Forward On-Voltage	V_F	I_F = 75 A, T_C = 25 °C	—	1.55	1.9	V
		I_F = 75 A, T_C = 150 °C	—	1.52	—	V
Gate Threshold Voltage	$V_{GE(th)}$	V_{CE} = V_{GE}, I_C = 250 µA	3.2	4.0	4.8	V
Collector Cut-off Current	I_{CES}	V_{GE} = 0 V, V_{CE} = 650 V	—	—	50	µA
Gate-Emitter Leakage Current	I_{GES}	V_{CE} = 0 V, V_{GE} = ± 20 V	—	—	±100	nA

Dynamic Electrical Characteristics (T_C = 25 °C, Unless Otherwise Specified)

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Input Capacitance	C_{ies}	V_{CE} = 30 V, V_{GE} = 0 V, f = 1 MHz	—	4823	—	pF
Output Capacitance	C_{oes}		—	131	—	
Reverse Transfer Capacitance	C_{res}		—	21	—	
Total Gate Charge	Q_g	V_{CE} = 520 V, V_{GE} = 15 V, I_C = 75 A	—	184	—	nC
Gate-Emitter Charge	Q_{ge}		—	33	—	
Gate-Collector Charge	Q_{gc}		—	48	—	

IGBT Switching Characteristics (Inductive Load, T_C = 25 °C, unless otherwise specified)

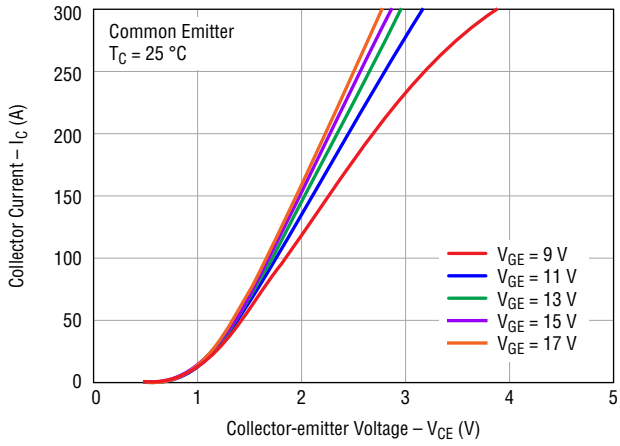
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Turn-on Delay Time	$t_{d(on)}$	V_{CE} = 400 V, V_{GE} = 15 V, I_C = 75 A, R_G = 10 Ω	—	35	—	ns
Current Rise Time	t_r		—	39	—	ns
Turn-off Delay Time	$t_{d(off)}$		—	194	—	ns
Current Fall Time	t_f		—	35	—	ns
Turn-on Switching Energy	E_{on}		—	1.56	—	mJ
Turn-off Switching Energy	E_{off}		—	1.07	—	mJ
Total Switching Energy	E_{ts}		—	2.63	—	mJ

Diode Switching Characteristics (T_C = 25 °C, unless otherwise specified)

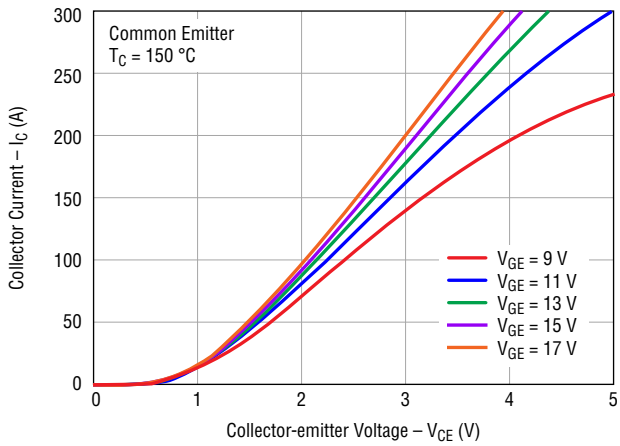
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Reverse Recovery Time	t_{rr}	dI_F/dt = 200 A/μs, I_F = 75 A	—	123	—	ns
Reverse Recovery Charge	Q_{rr}		—	0.4	—	uC

Electrical Characteristic Performance

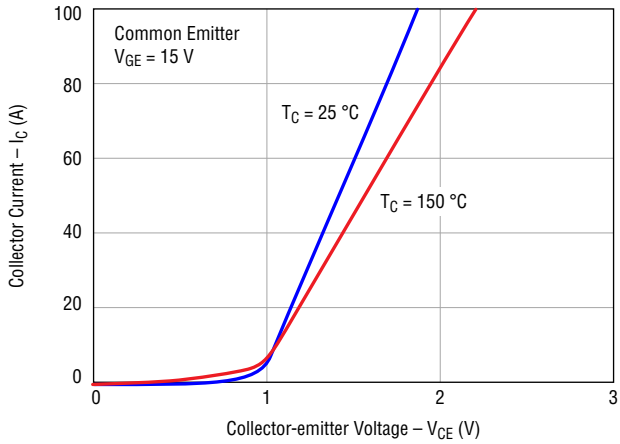
Typical Output Characteristics



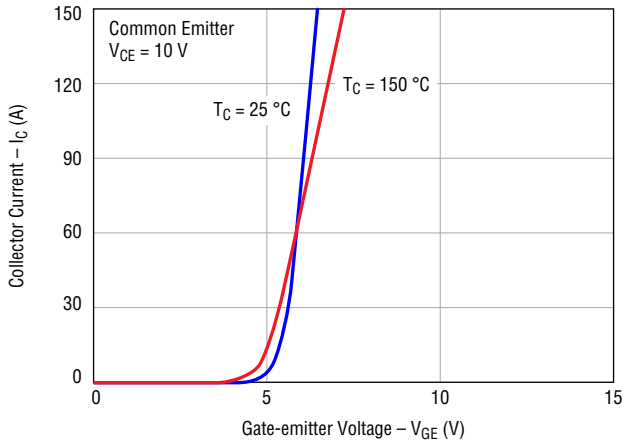
Typical Output Characteristics



Typical Saturation Voltage Characteristics

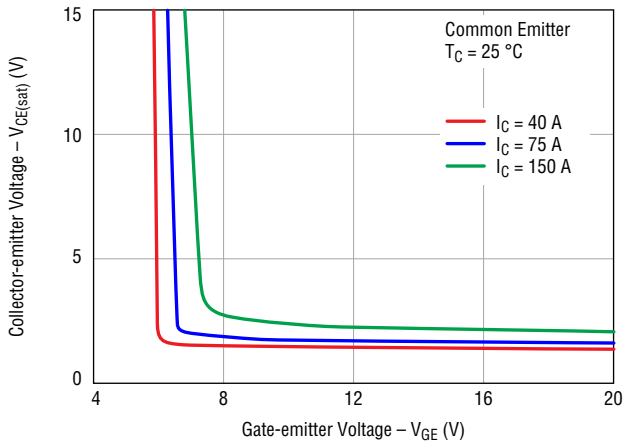


Typical Transfer Characteristics

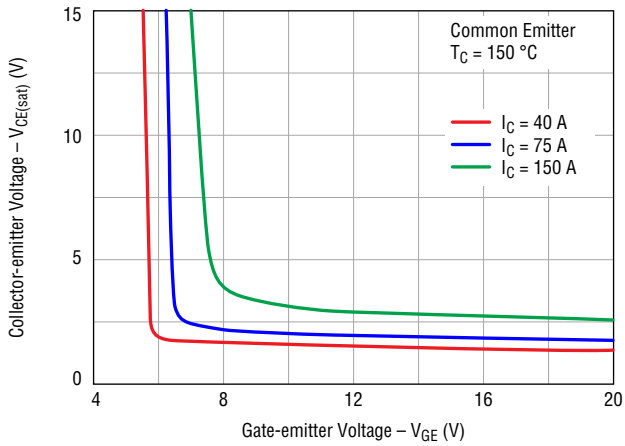


Electrical Characteristic Performance (continued)

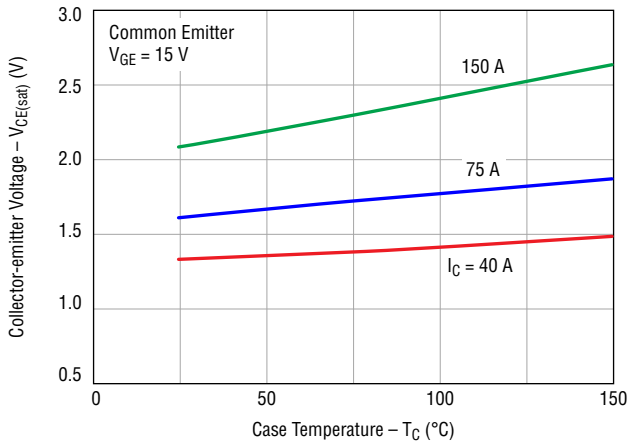
Typical Saturation Voltage Drop vs V_{GE}



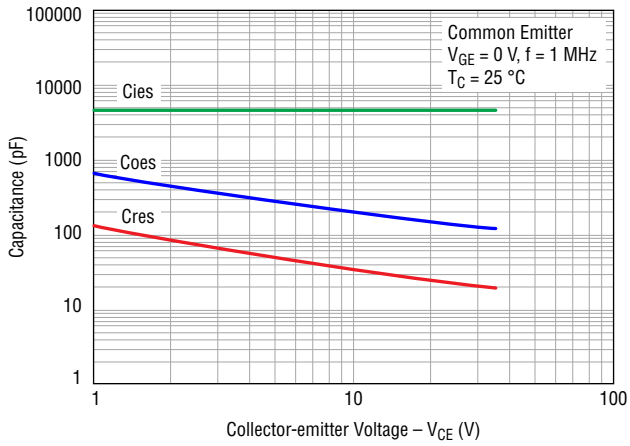
Typical Saturation Voltage Drop vs V_{GE}



Typical $V_{CE(sat)}$ vs Case Temperature

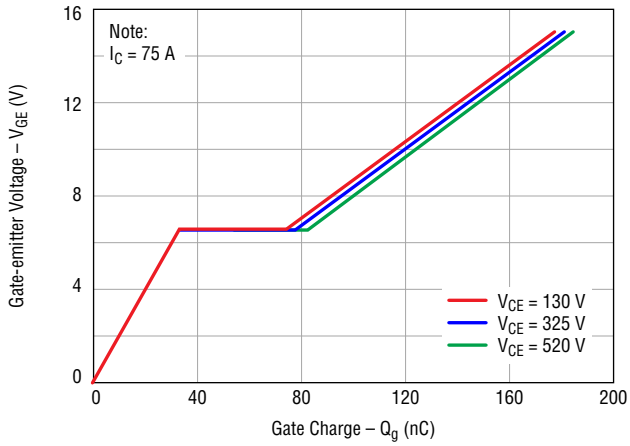


Typical Capacitance Characteristics

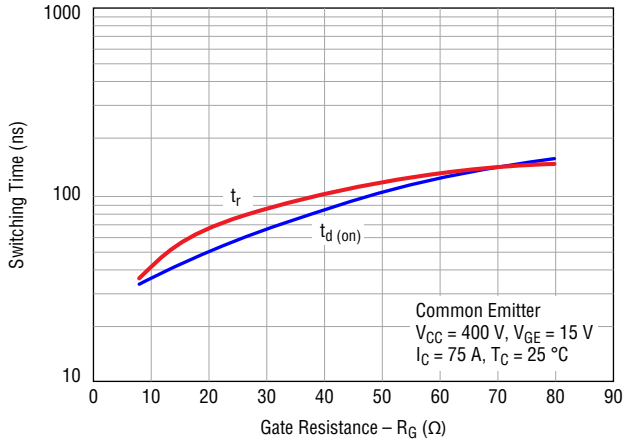


Electrical Characteristic Performance (continued)

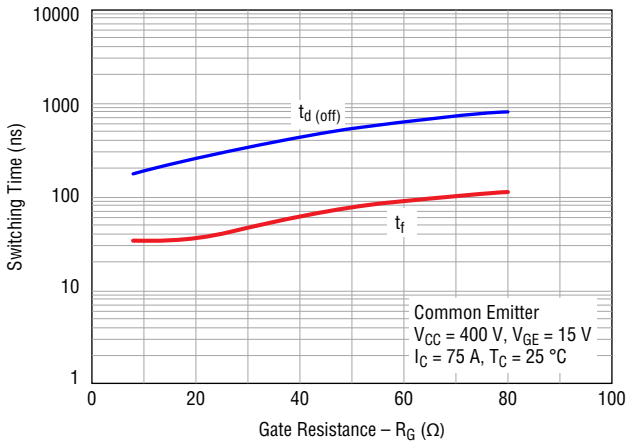
Typical Gate Charge Characteristics



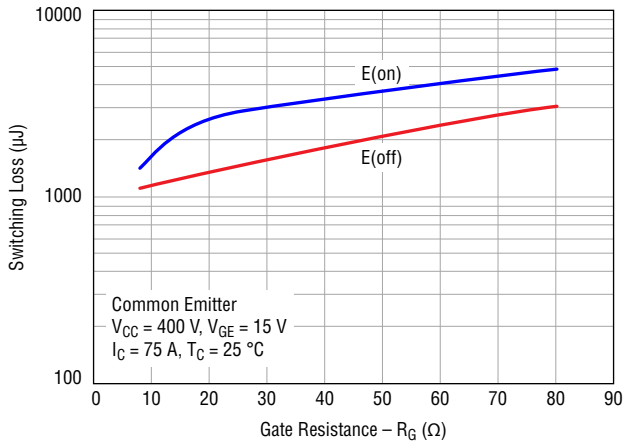
Typical Turn-on Characteristics vs Gate Resistance



Typical Turn-off Characteristics vs Gate Resistance

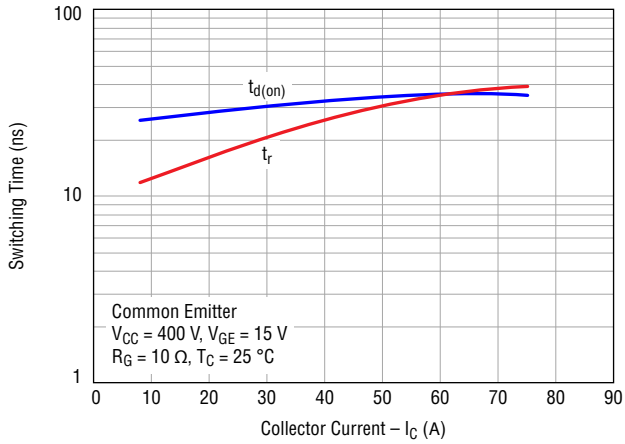


Typical Switching Loss vs Gate Resistance

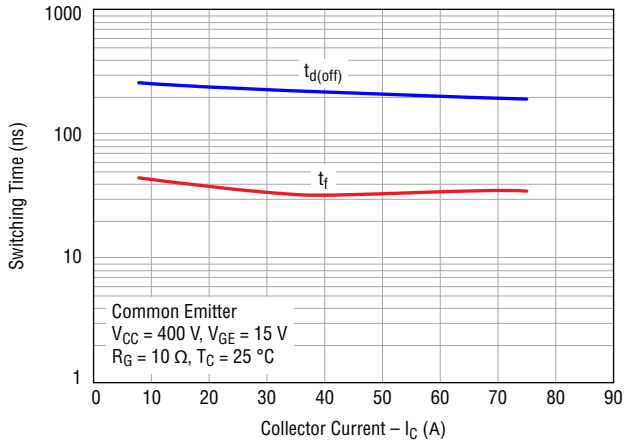


Electrical Characteristic Performance (continued)

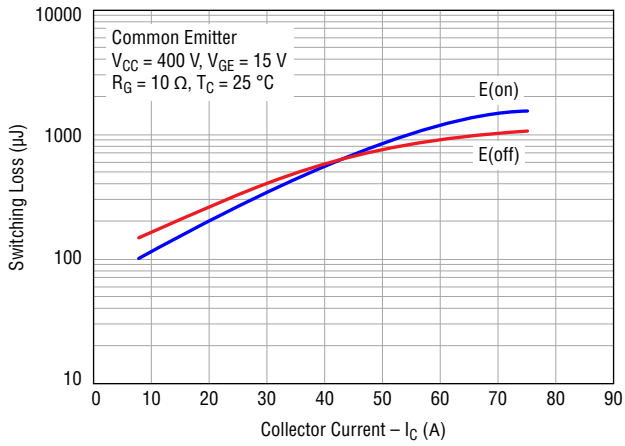
Typical Turn-on Characteristics vs Collector Current



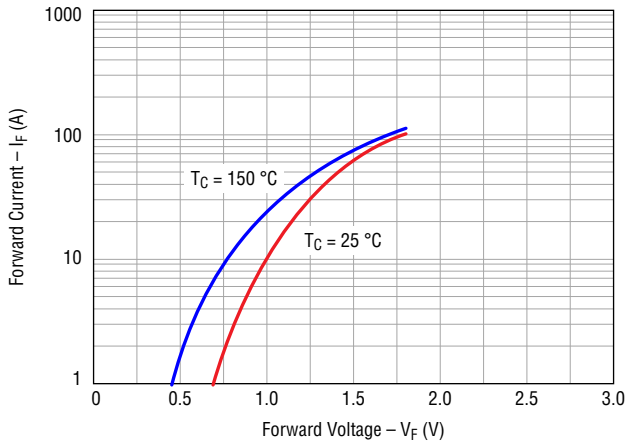
Typical Turn-off Characteristics vs Collector Current



Typical Switching Loss vs Collector Current

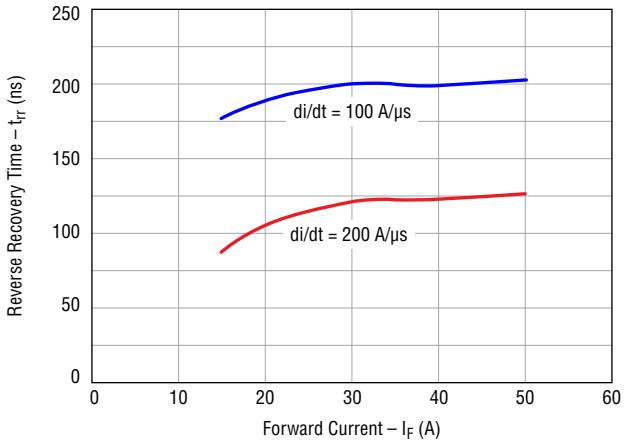


Typical Forward Characteristics

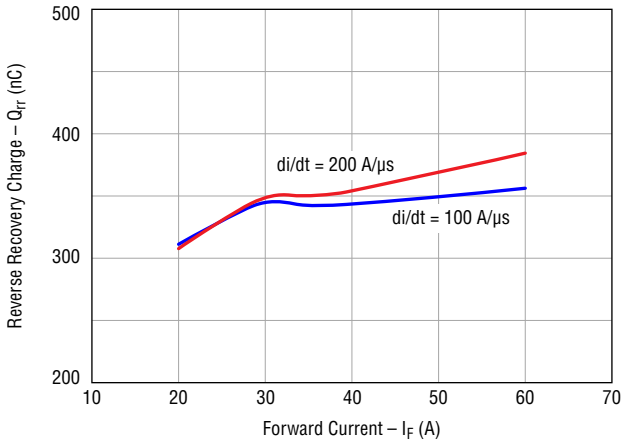


Electrical Characteristic Performance (continued)

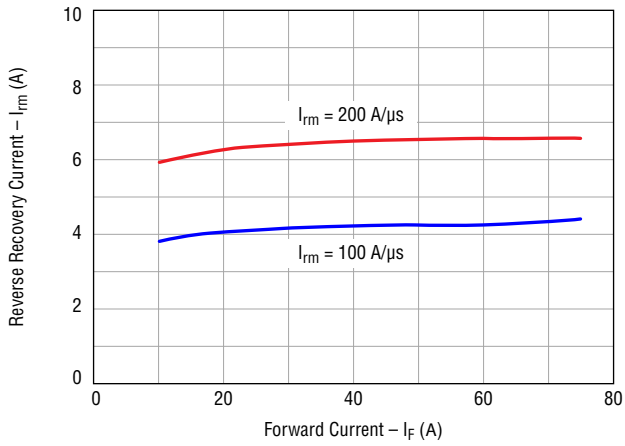
Typical Reverse Recovery Time vs Forward Current



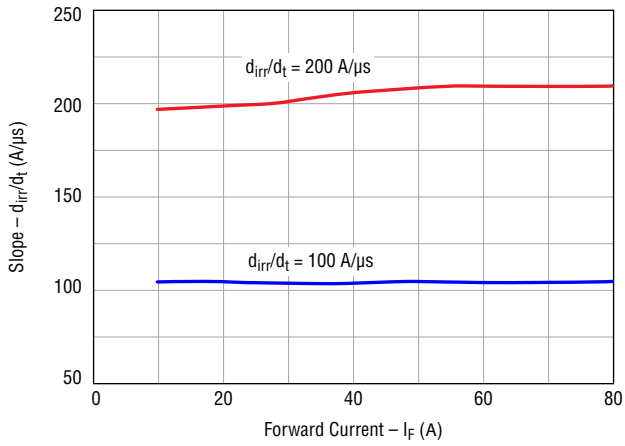
Typical Reverse Recovery Charge vs Forward Current



Typical Reverse Recovery Current vs Forward Current

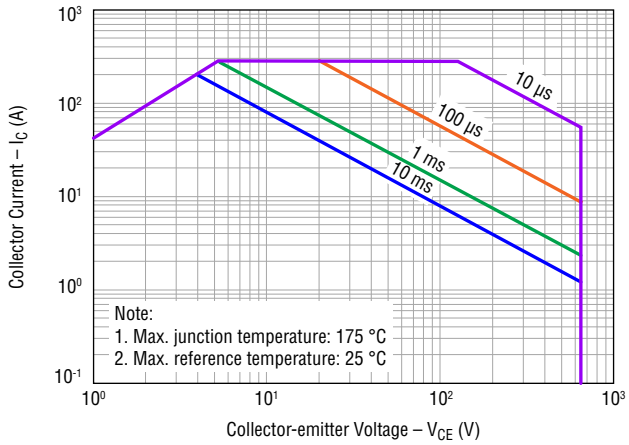


Slope vs Forward Current



Electrical Characteristic Performance (continued)

Forward Bias Safe Operating Area

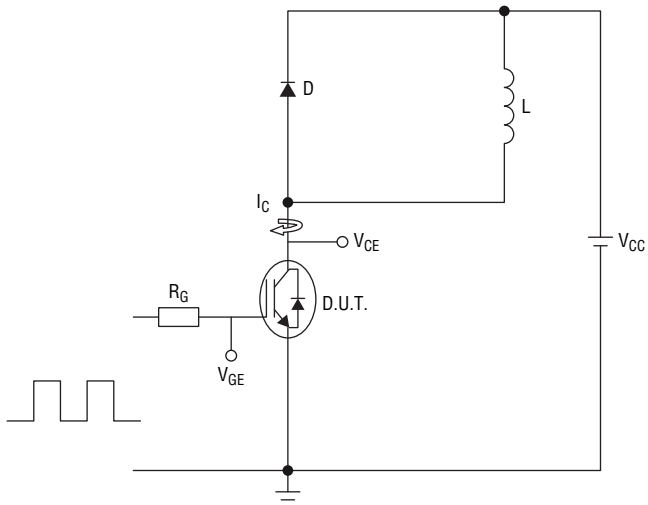


How to Order

B I D W 75 N 65 ES 5

- B = Bourns®
- I = IGBT
- Type
  - D = Discrete
- Package Code
  - W = TO-247-3L
- Current Rating
  - 75 = 75 A
- Device Type
  - N = N-channel
- Nominal Voltage (divided by 10)
  - 65 = 650 V
- Optimization
  - ES = Efficient Medium Speed
- Version Number

Inductive Load Test Circuit



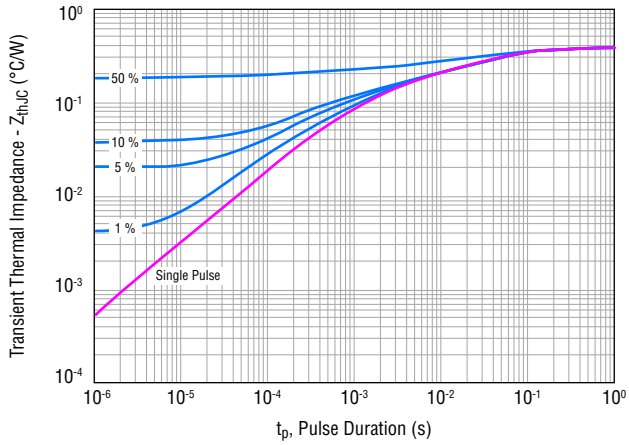
L = 100 μH, V_{CE} = 400 V, V_{GE} = 15 V, I_C = 75 A, R_G = 10 Ω

Environmental Characteristics

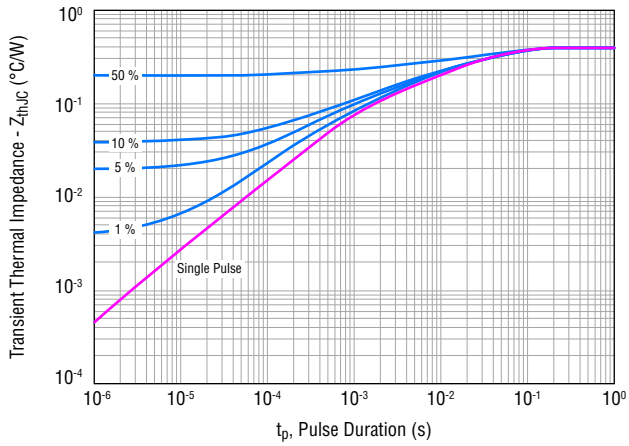
ESD Class (HBM).....2

Electrical Characteristic Performance (continued)

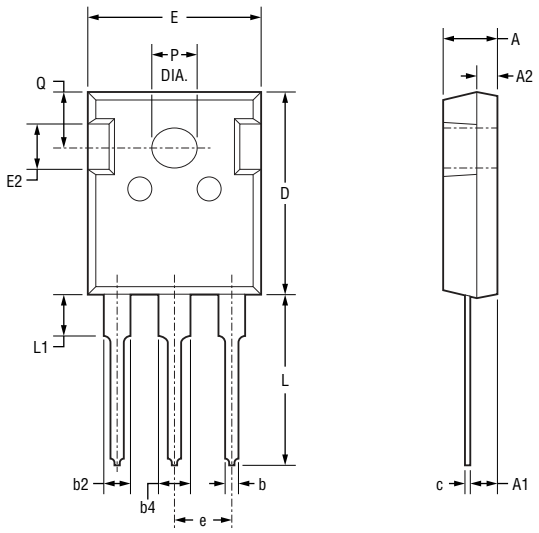
IGBT Transient Thermal Impedance vs $t_{p(on)}$ Duration ($D=t_p/T$)



Diode Transient Thermal Impedance vs $t_{p(on)}$ Duration ($D=t_p/T$)



Product Dimensions



DIMENSIONS: MM / (INCHES)

Symbol	Min.	Nom.	Max.
A	4.80 (.189)	5.00 (.197)	5.20 (.205)
A1	2.21 (.087)	2.41 (.095)	2.59 (.102)
A2	1.85 (.073)	2.00 (.079)	2.15 (.085)
b	1.11 (.044)	—	1.36 (.054)
b2	1.91 (.075)	—	2.25 (.089)
b4	2.91 (.115)	—	3.25 (.128)
c	0.51 (.020)	—	0.75 (.030)
D	20.80 (.819)	21.00 (.827)	21.30 (.839)
E	15.50 (.610)	15.80 (.622)	16.10 (.634)
E2	4.40 (.173)	5.00 (.197)	5.20 (.205)
e		5.44 (.214) BSC	
L	19.72 (.776)	19.92 (.784)	20.22 (.796)
L1	—	—	4.30 (.169)
P	3.40 (.134)	—	3.80 (.150)
Q	5.60 (.220)	5.80 (.228)	6.00 (.236)

Packaging Specifications

BIDW75N65ES5..... 30 pieces per tube

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REV. 11/23

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